

EE210A: Microelectronics I

Problem Set 8

Instructor: Imon Mondal, imon@iitk.ac.in

1) : Consider $V_{DD}=5V$, $R_1 = 3k\Omega$, $R_2 = 2k\Omega$, $R_3 = 1k\Omega$, $R_D = 3k\Omega$, $|V_{tp}| = 1V$, $\mu_p C_{ox} = 100\mu A/V^2$, $W/L = 20$, $C_1 = 10pF$, $C_2 = 1pF$ (Ignore CLM)

a) : Find $v_o(j\omega)/v_i(j\omega)$.

b) : Plot the bode-plot for the gain and phase of $v_o(j\omega)/v_i(j\omega)$.

c) : What are the corner frequencies?

d) : What are the pole and zero locations of $v_o(s)/v_i(s)$?

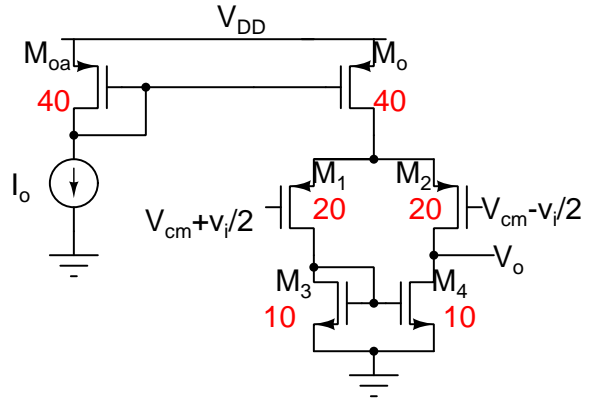


Figure 2: Problem 2.

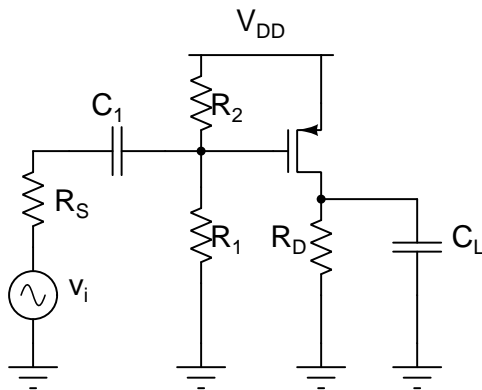


Figure 1: Problem 1.

2) : Consider $\mu_n C_{ox} = 200\mu A/V^2$, $\mu_p C_{ox} = 100\mu A/V^2$, $I_o = 2mA$, $|V_{tp}| = 1V$, $\lambda_n = \lambda_p = 0.1V^{-1}$ and $V_{DD} = 3V$.

a) : Find v_o/v_i (make necessary approximations).

b) : Find the $\max(V_{cm})$ and $\min(V_{cm})$ which you can have while keeping all transistors in saturation. Assume $V_{o(quiet)} = 1V, 1.5V$

c) : How will you change the design to increase $\max(V_{cm})$ by 500mV?

- 3) : Refer figure3.
- a) : Find v_{o1}/v_i and v_{o2}/v_i symbolically.
- b) : Find incremental and quiescent v_x .
- c) : Find the max and min V_i which will keep all the transistors in saturation. Assume $R \ll r_{ds}$ for any transistor.
- d) : If the inputs to M_1 and M_2 are $V_{cm} + v_{icm}$, then find the v_{o1}/v_{icm} , and the swing limits of v_{icm} .

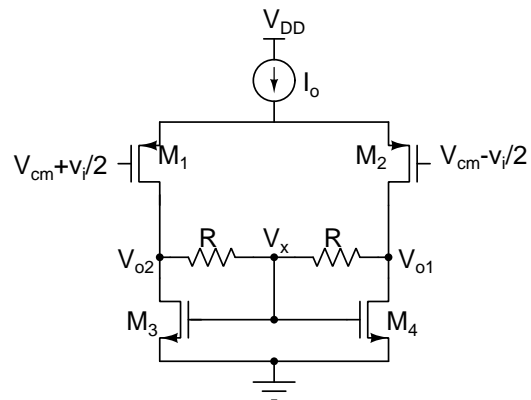


Figure 3: Problem 3.

- 4) : Assume M_1 is biased in saturation, $C_1 \rightarrow \infty, R_1 || R_2 \rightarrow \infty$. (Ignore CLM)
- a) : Find $v_o(s)/v_i(s)$.
- b) : Sketch the bode-magnitude plot of $|v_o(j\omega)/v_i(j\omega)|$ while marking the poles and zeros. Assume the poles are far apart from each other.

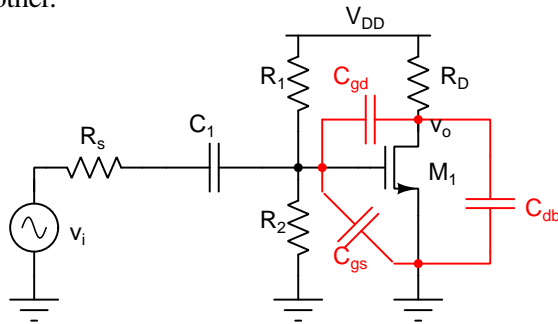


Figure 4: Problem 4.

- 5) : Figure (i) and (ii) shows two possible output stages, being driven by a G_m (which has an incremental o/p resistance r_1). Assume $G_m r_1 = 100$.
- a) : Find the quiescent V_o in (i) and (ii).
- b) : Find the open-loop o/p impedance in both the architectures.
- c) : Find the max and min possible V_o . Assume I_o requires at least 100mV across it to behave like a current source.

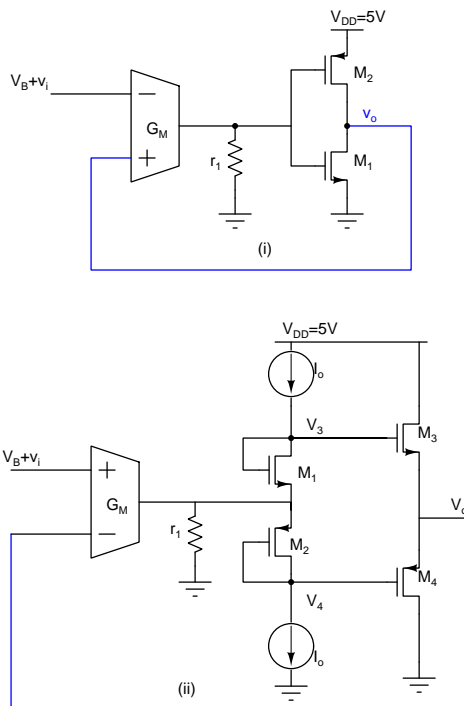


Figure 5: Problem 5.